

SIDE-LOOK PACKAGE PIN PHOTODIODE

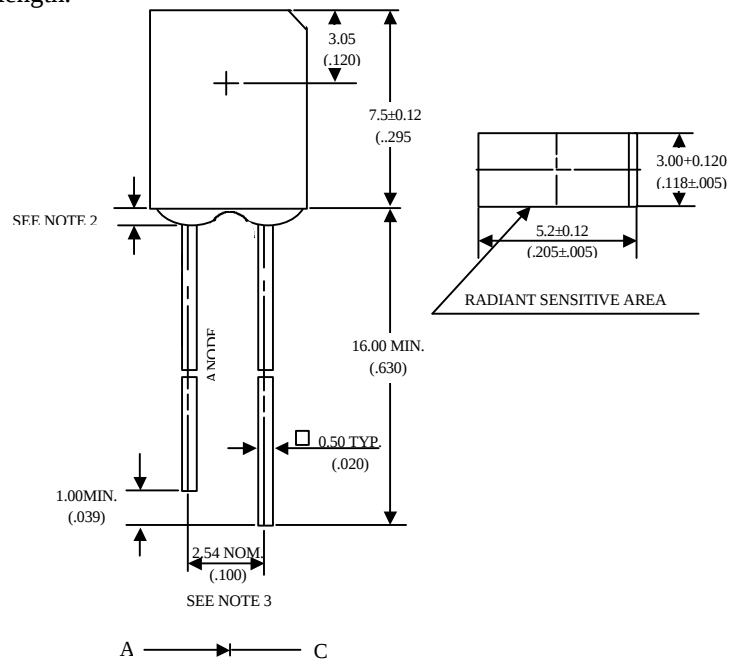
MID-7341C

Description

The MID-7341C is a photodiode mounted in water clear plastic package and suitable for the variety wavelength.

Package Dimensions

Unit : mm (inches)



Features

- High photo sensitivity
- Low junction capacitance
- High cut-off frequency
- Fast switching time

Notes :

1. Tolerance is ± 0.25 mm (.010") unless otherwise noted.
2. Protruded resin under flange is 1.0 mm (.040") max.
3. Lead spacing is measured where the leads emerge from the package.

Absolute Maximum Ratings

@ $T_A = 25^\circ\text{C}$

Parameter	Maximum Rating	Unit
Power Dissipation	100	mW
Operating Temperature Range	-55°C to $+100^\circ\text{C}$	
Storage Temperature Range	-55°C to $+100^\circ\text{C}$	
Lead Soldering Temperature	260°C for 5 seconds	

UNi

Unity Opto Technology Co., Ltd.

02/04/2002

Optical-Electrical Characteristics

@ T_A=25°C

Parameter	Test Conditions	Symbol	Min.	Typ.	Max.	Unit
Reverse Breakdown Voltage	I _R =0.1mA Ee=0	V _{(BR)R}	30			V
Reverse Dark Current	V _R =10V Ee=0	I _D			30	nA
Open Circuit Voltage	λ=940nm Ee=0.1mW/cm ²	V _{OC}		350		mV
Rise Time	V _R =10V λ=940nm R _L =50Ω	T _r		50		nsec
Fall Time		T _f		50		
Light Current	V _R =5V, λ=940nm Ee=0.1mW/cm ²	I _L		9		μA
Total Capacitance	V _R =3V, f=1MHz Ee=0	C _T		25		pF

Typical Optical-Electrical Characteristic Curves

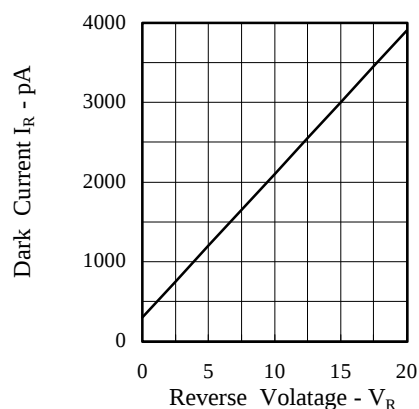


FIG.1 DARK CURRENT VS REVERSE VOLTAGE
TEMP=25°C, Ee=0 mW/cm²

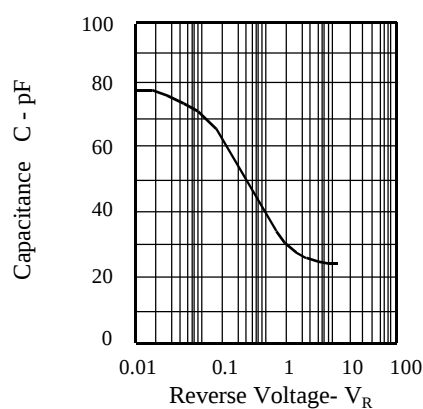


FIG.2 CAPACITANCE VS. REVERSE VOLTAGE
F=1MHz, Ee=0mW/cm²

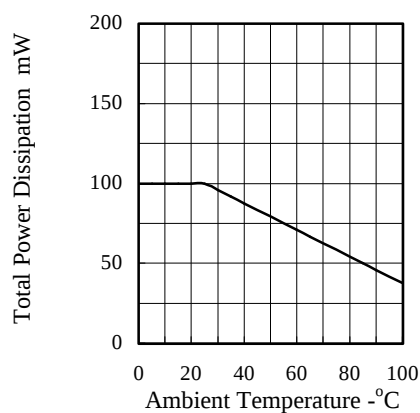


FIG.3 TOTAL POWER DISSIPATION
VS. AMBIENT TEMPERATURE

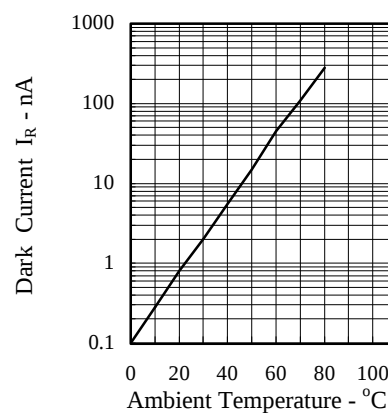


FIG.4 DARK CURRENT VS AMBIENT TEMPERATURE
V_R=10, Ee=0 mw/cm²

Typical Optical-Electrical Characteristic Curves

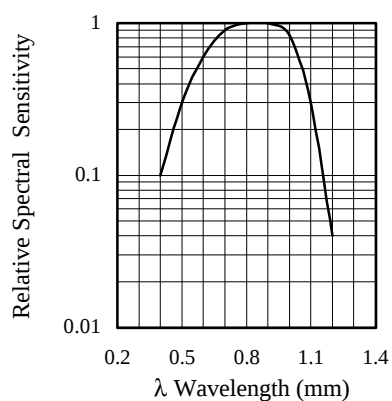


FIG.5 RELATIVE SPECTRAL SENSITIVITY VS. WAVELENGTH

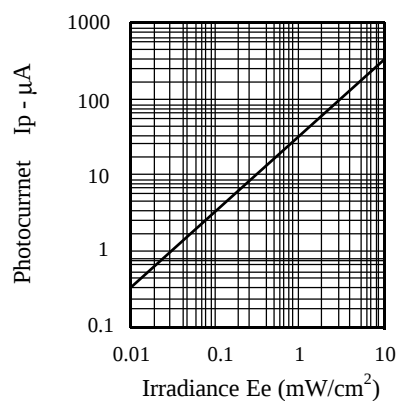


FIG.6 PHOTOCURRENT VS. IRRADIANCE

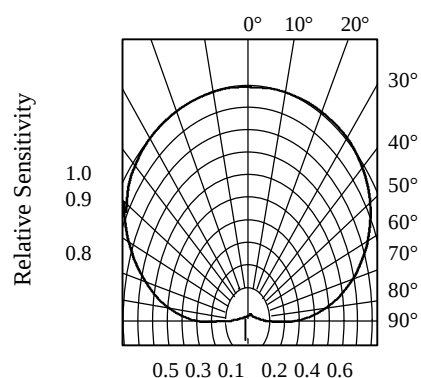


FIG.7 SENSITIVITY DIAGRAM